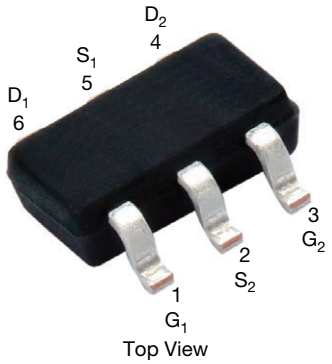
Automotive Dual P-Channel 30 V (D-S) 175 °C MOSFET

TSOP-6 Dual



Top View

Marking code: 8X

FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % R_g and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

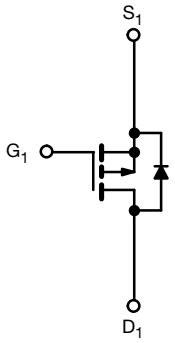
AUTOMOTIVE GRADE

Pb-free

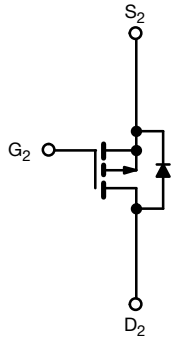
RoHS COMPLIANT

HALOGEN FREE

PRODUCT SUMMARY	
V_{DS} (V)	-30
$R_{DS(on)}$ (Ω) at V_{GS} = -10 V	-0.110
$R_{DS(on)}$ (Ω) at V_{GS} = -4.5 V	-0.185
I_D (A)	-2.75
Configuration	Dual
Package	TSOP-6



P-Channel MOSFET



P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise noted)				
PARAMETER		**SYMBOL**	**LIMIT**	**UNIT**
Drain-source voltage		V_{DS}	-30	V
Gate-source voltage		V_{GS}	± 20	
Continuous drain current (T_J = 150 °C) [a]	T_C = 25 °C	I_D	-3	A
	T_C = 125 °C		-1.74	
Pulsed drain current		I_{DM}	-11	
Continuous source current (diode conduction) [a]		I_S	-2.1	
Maximum power dissipation [a]	T_C = 25 °C	P_D	1.67	W
	T_C = 125 °C		0.56	
Unclamped inductive surge UIS		I_{AV}	-5	A
Operating junction and storage temperature range		T_J, T_{stg}	-55 to +175	°C

THERMAL RESISTANCE RATINGS				
PARAMETER		**SYMBOL**	**LIMIT**	**UNIT**
Maximum junction-to-ambient [a]	Steady state	R_{thJA}	150	°C/W
Maximum junction-to-foot (drain)	Steady state	R_{thJF}	90	

Note

a. Surface mounted on 1" x 1" FR4 board

SPECIFICATIONS (T_J = 25°C, unless otherwise noted)							
PARAMETER	**SYMBOL**	**TEST CONDITIONS**		**MIN.**	**TYP.**	**MAX.**	**UNIT**
Static							
Gate threshold voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = -250 µA		-1.5	-	-2.5	V
Gate-body leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V		-	-	± 100	nA
Zero gate voltage drain current	I_{DSS}	V_{GS} = 0 V	V_{DS} = -30 V	-	-	-1	µA
		V_{GS} = 0 V	V_{DS} = -30 V, T_J = 175 °C	-	-	-50	
On-state drain current [a]	$I_{D(on)}$	V_{GS} = -10 V	V_{DS} ≤ -5 V	-4	-	-	A
Drain-source on-state resistance [a]	$R_{DS(on)}$	V_{GS} = -10 V	I_D = -1.5 A	-	0.085	0.133	Ω
		V_{GS} = -4.5 V	I_D = -2 A	-	0.135	0.185	
Forward transconductance [a]	g_{fs}	V_{DS} = -5 V, I_D = -1 A		-	4.2	-	S
Diode forward voltage [a]	V_{SD}	I_S = -0.5 A, V_{GS} = 0 V		-	-0.83	-1.10	V
Dynamic [b]							
Input capacitance	C_{iss}	V_{GS} = 0 V	V_{DS} = -15 V	-	456	570	pF
Output capacitance	C_{oss}			-	85	106	
Reverse capacitance	C_{rss}			-	59	74	
Total gate charge	Q_g	V_{GS} = -10 V	V_{DS} = -15 V, I_D = -3 A	-	9.7	12.2	nC
Gate-source charge	Q_{gs}			-	1.3	-	
Gate-drain charge	Q_{gd}			-	2	-	
Gate resistance	R_g	f = 1 MHz		9	-	24	Ω
Turn-on delay time	$t_{d(on)}$	V_{DD} = -10 V, R_L = 10 Ω, I_D ≅ -1 A, V_{GEN} = -10 V, R_g = 1 Ω		-	6.6	8.3	ns
Rise time	t_r			-	2.4	3	
Turn-off delay time	$t_{d(off)}$			-	18.4	23	
Fall time	t_f			-	2.2	2.8	
Source-Drain Diode Ratings and Characteristic [b]							
Pulsed current	I_{SM}			-	-	-11	A
Forward voltage	V_{SD}	I_F = 0.5 A, V_{GS} = 0 V		-	-0.83	-1.1	V
Reverse recovery fall time	t_a	V_{DD} = -24 V, I_{FM} = -1.5 A, di/dt = 100 A/µs, R = 160 Ω, L = 1 mH, pulse W = 2 µs		-	9.1	-	ns
Reverse recovery rise time	t_b			-	4.8	-	ns
Body diode reverse recovery time	t_{rr}			-	14	28	ns
Body diode reverse recovery charge	Q_{rr}			-	9	18	µC
Body diode peak reverse recovery current	$I_{RM(REC)}$			-	-1.4	-	A

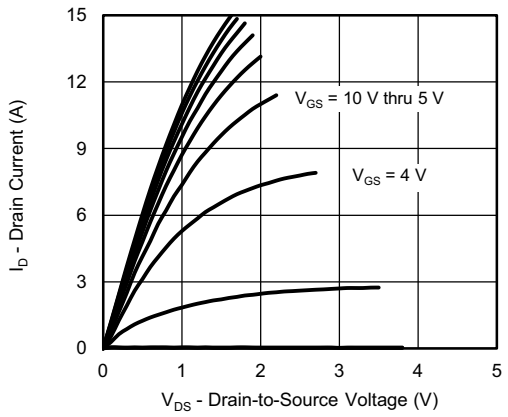
Notes

a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %

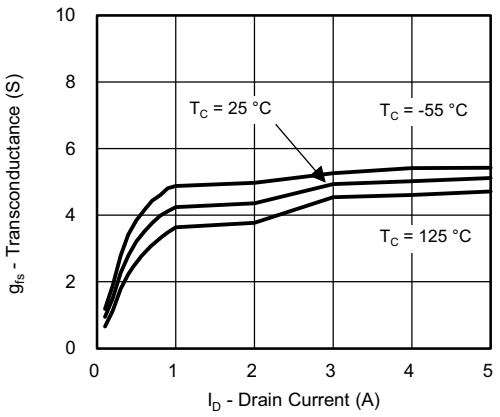
b. Guaranteed by design, not subject to production testing

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

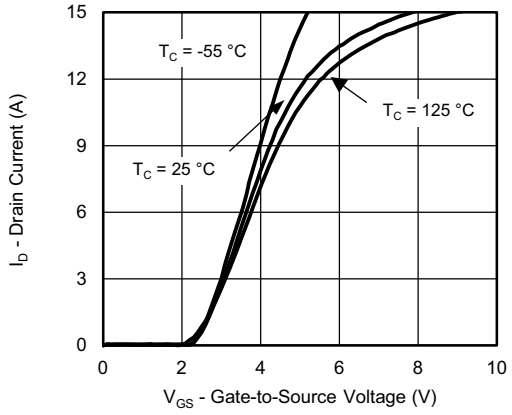
TYPICAL CHARACTERISTICS (25 °C unless otherwise noted)



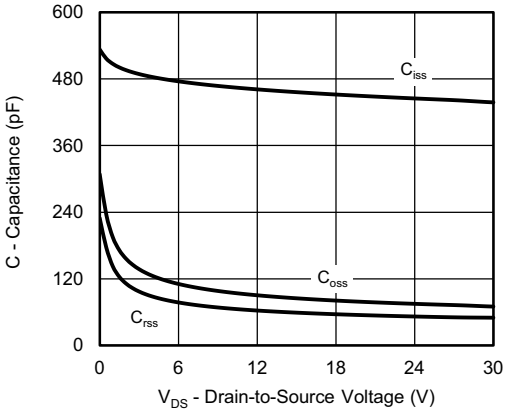
Output Characteristics



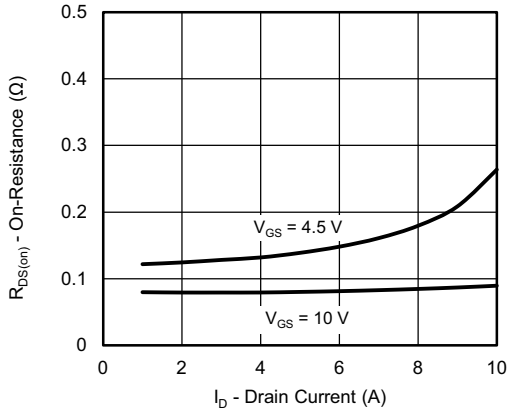
Transconductance



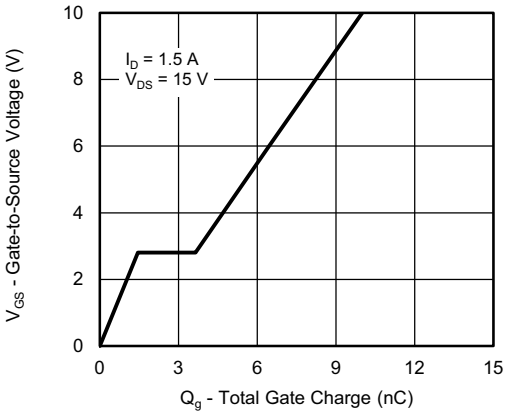
Transfer Characteristics



Capacitance

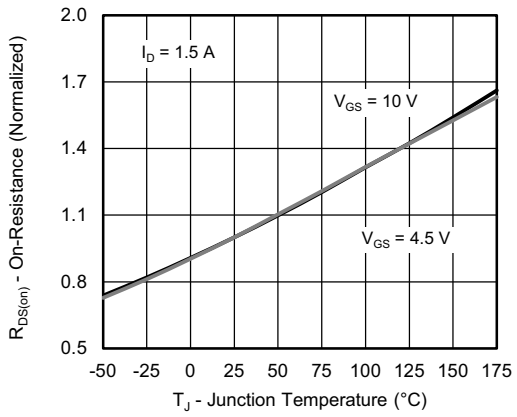


On-Resistance vs. Drain Current

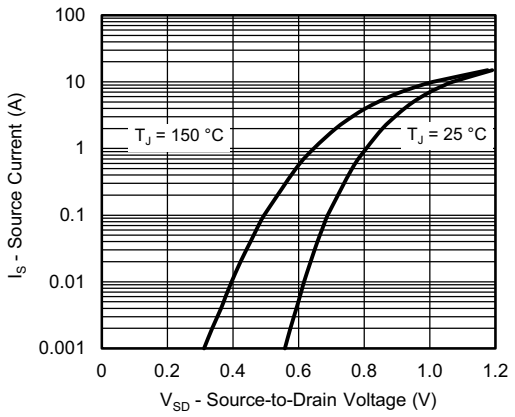


Gate Charge

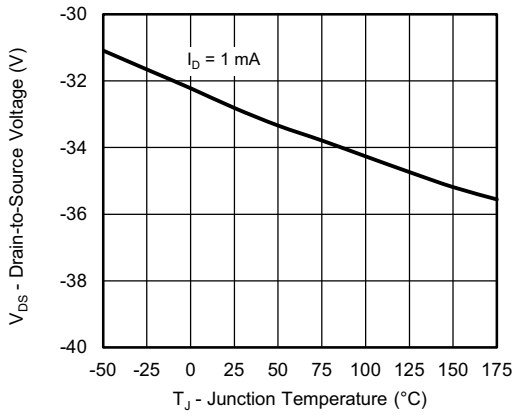
TYPICAL CHARACTERISTICS (25 °C unless otherwise noted)



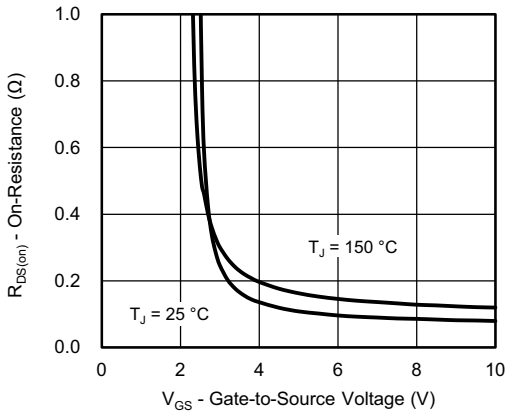
On-Resistance vs. Junction Temperature



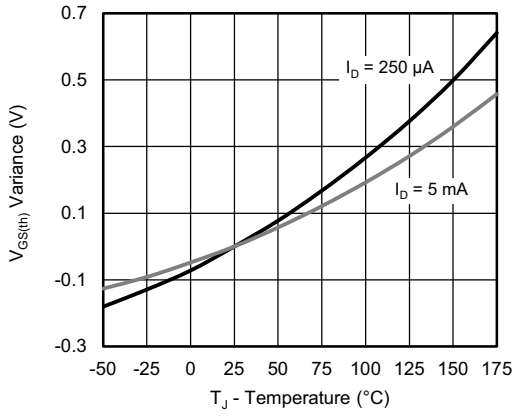
Source-Drain Diode Forward Voltage



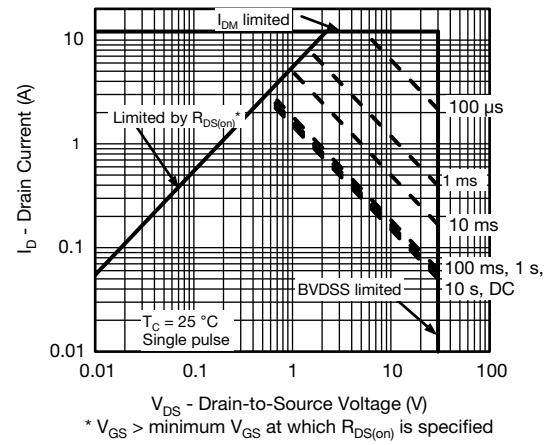
Drain Source Breakdown vs. Junction Temperature



On-Resistance vs. Gate-to-Source Voltage

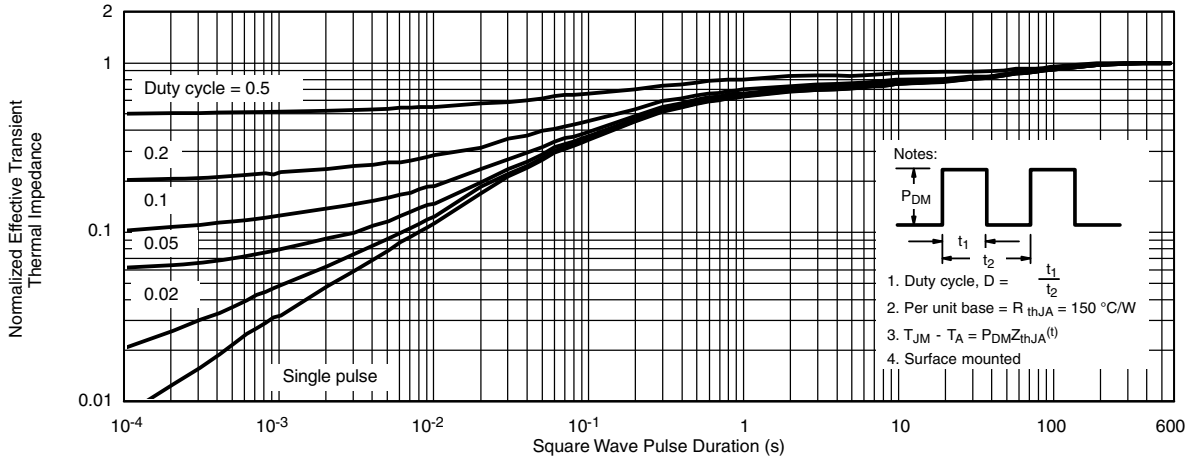


Threshold Voltage

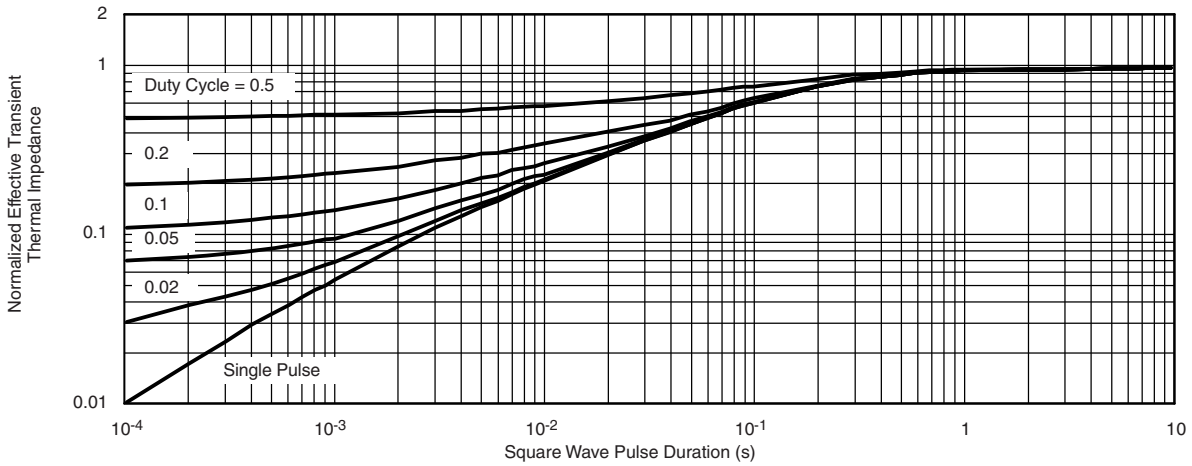


Safe Operating Area, Junction-to-Case

TYPICAL CHARACTERISTICS (25 °C unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Foot

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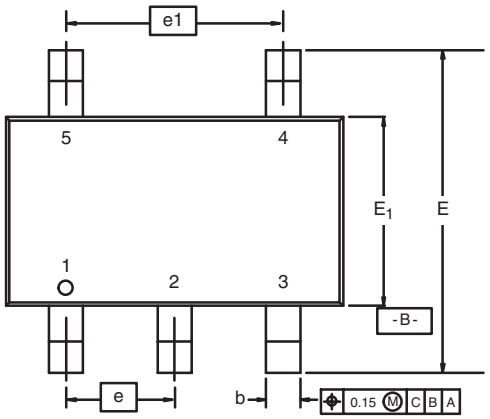
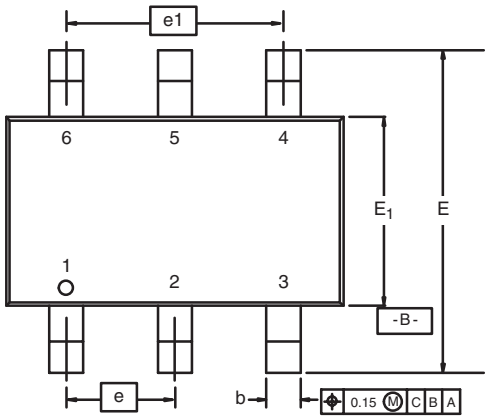
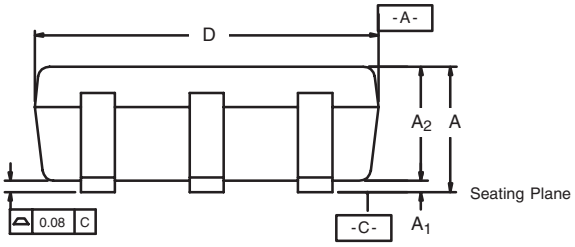
TSOP: 5/6–LEAD
JEDEC Part Number: MO-193C

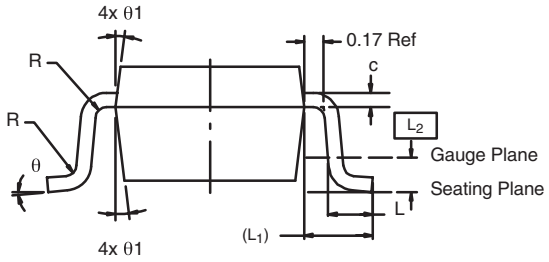


5-LEAD TSOP



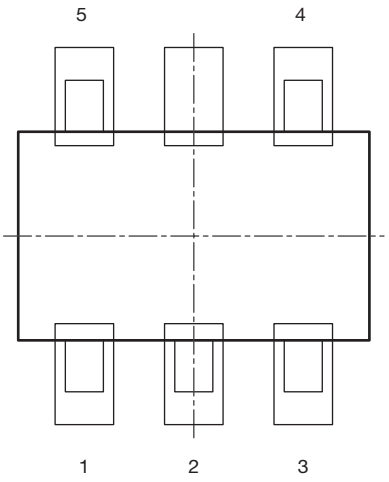
6-LEAD TSOP



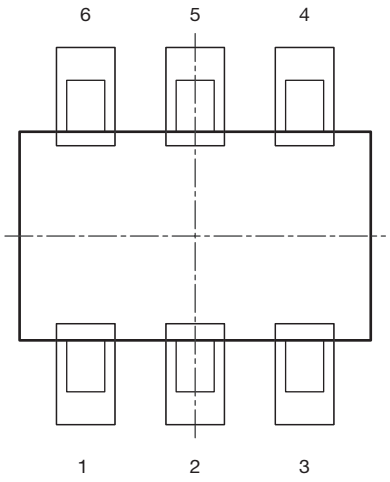


Dim	MILLIMETERS			INCHES		
	Min	Nom	Max	Min	Nom	Max
A	0.91	-	1.10	0.036	-	0.043
A_1	0.01	-	0.10	0.0004	-	0.004
A_2	0.90	-	1.00	0.035	0.038	0.039
b	0.30	0.32	0.45	0.012	0.013	0.018
c	0.10	0.15	0.20	0.004	0.006	0.008
D	2.95	3.05	3.10	0.116	0.120	0.122
E	2.70	2.85	2.98	0.106	0.112	0.117
E_1	1.55	1.65	1.70	0.061	0.065	0.067
e	0.95 BSC			0.0374 BSC		
e_1	1.80	1.90	2.00	0.071	0.075	0.079
L	0.32	-	0.50	0.012	-	0.020
L_1	0.60 Ref			0.024 Ref		
L_2	0.25 BSC			0.010 BSC		
R	0.10	-	-	0.004	-	-
θ	0°	4°	8°	0°	4°	8°
θ_1	7° Nom			7° Nom		
ECN: C-06593-Rev. I, 18-Dec-06 DWG: 5540						

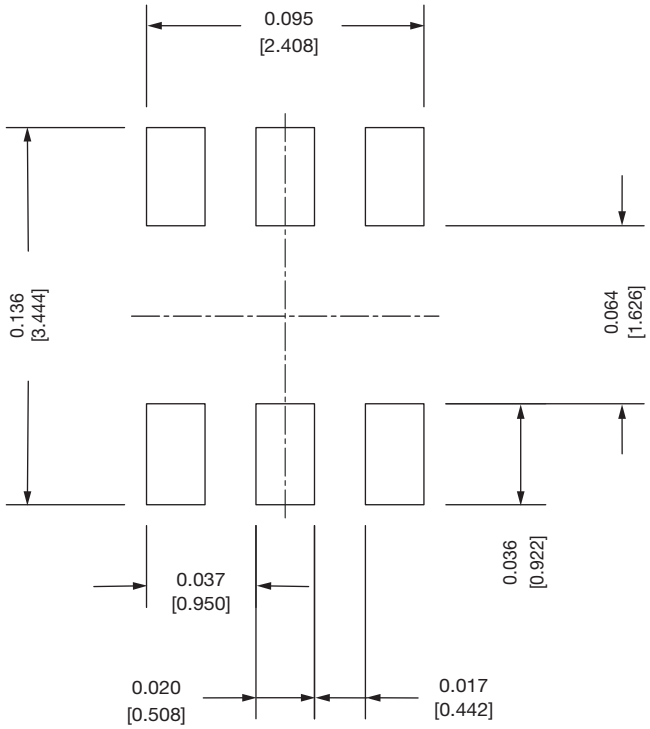
Recommended Land Pattern For TSOP-5L / TSOP-6L



TSOP 5L



TSOP 6L



Note

- All dimensions are in inches (millimeter)

ECN: C22-0860-Rev. B, 24-Oct-2022 DWG: 3010

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